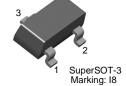


### J108/J109/J110/MMBFJ108

#### **N-Channel Switch**

- · This device is designed for digital switching applications where very low on resistance is mandatory.
- Sourced from Process 58.





1. Drain 2. Source 3. Gate

1. Drain 2. Source 3. Gate

### **Absolute Maximum Ratings \*** T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter	Value	Units
$V_{DG}$	Drain-Gate Voltage	25	V
$V_{GS}$	Gate-Source Voltage	-25	V
I <sub>GF</sub>	Forward Gate Current	10	mA
T <sub>J</sub> , T <sub>stg</sub>	Operating and Storage Junction Temperature Range	-55 ~ +150	°C

<sup>\*</sup> These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

- These ratings are based on a maximum junction temperature of 150 degrees C.
   These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

### Electrical Characteristics T<sub>A</sub>=25°C unless otherwise noted

Symbol	Parameter	Test Condition	on	Min.	Max.	Units
Off Charac	teristics					
V <sub>(BR)GSS</sub>	Gate-Source Breakdwon Voltage	$I_G = -10\mu A, V_{DS} = 0$		-25		V
I <sub>GSS</sub>	Gate Reverse Current	$V_{GS} = -15V, V_{DS} = 0$			-3.0	nA
		$V_{GS} = -15V, V_{DS} = 0, T_A = 100^{\circ}C$			-200	nA
V <sub>GS</sub> (off)	Gate-Source Cutoff Voltage	$V_{DS} = 15V, I_{D} = 10nA$	108	-3.0	-10	V
			109	-2.0	-6.0	V
			110	-0.5	-4.0	V
On Charact	teristics					
I <sub>DSS</sub>	Zero-Gate Voltage Drain Current *	$V_{DS} = 15V, I_{GS} = 0$	108	80		mA
			109	40		mA
			110	10		mA
r <sub>DS</sub> (on)	Drain-Source On Resistance	$V_{DS} \le 0.1V, V_{GS} = 0$	108		8.0	Ω
			109		12	Ω
			110		18	Ω
Small Sign	al Characteristics					
C <sub>da</sub> (on)	Drain Gate & Source Gate On	$V_{DS} = 0$ , $V_{GS} = 0$ , $f = 1.0MHz$			85	pF
C <sub>sg</sub> (off)	Capacitance					
C <sub>dg</sub> (on)	Drain-Gate Off Capacitance	V <sub>DS</sub> = 0, V <sub>GS</sub> = -10, f = 1.0MHz			15	pF
C <sub>sq</sub> (off)	Source-Gate Off Capacitance	$V_{DS} = 0$ , $V_{GS} = -10$ , $f = 1$ .	0MHz		15	pF

\* Pulse Test: Pulse Width ≤ 300μs, Duty Cycle ≤ 2.0%

# Thermal Characteristics $\rm T_A=25^{\circ}C$ unless otherwise noted

Symbol	Parameter	Ma	Lleito	
		J108 - 110	*MMBFJ108	Units
P <sub>D</sub>	Total Device Dissipation Derate above 25°C	625 5.0	350 2.8	mW mW/°C
$R_{\theta JC}$	Thermal Resistance, Junction to Case	125		°C/W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	357	556	°C/W

<sup>\*</sup> Device mounted on FR-4 PCB 1.6" × 1.6" × 0.06"

# **Typical Characteristics**

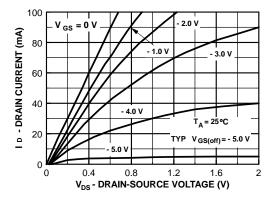


Figure 1. Common Drain-Source

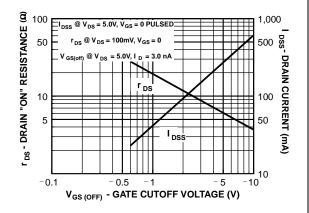


Figure 2. Parameter Interactions

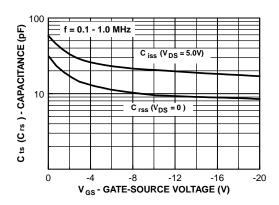


Figure 3. Common Drain-Source

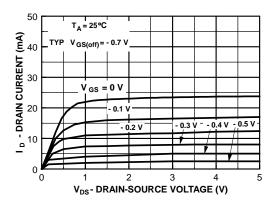


Figure 4. Common Drain-Source

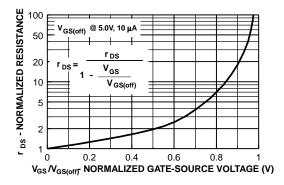


Figure 5. Normalized Drain Resistance vs Bias Voltage

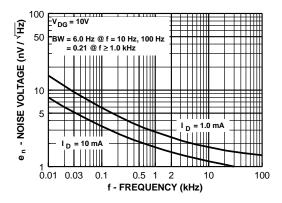


Figure 6. Noise Voltage vs Frequency

### **Typical Characteristics** (Continued)

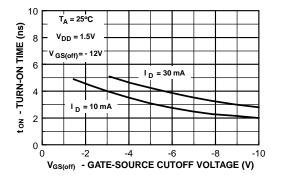


Figure 7. Switching Turn-On Time vs Gate-Source Cutoff Voltage

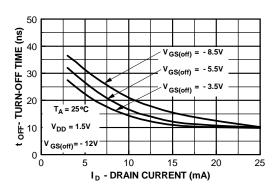


Figure 8. Switching Turn-On Time vs Drain Current

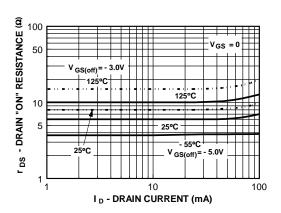


Figure 9. On Resistance vs Drain Current

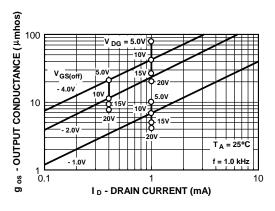


Figure 10. Output Conductance vs Drain Current

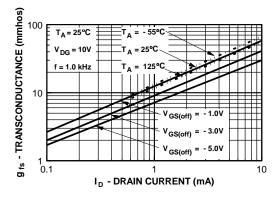


Figure 11. Transconductance vs Drain Current

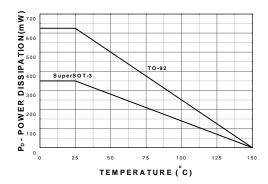
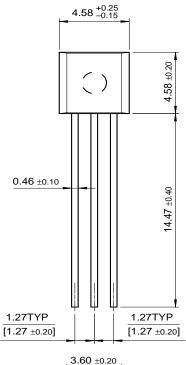
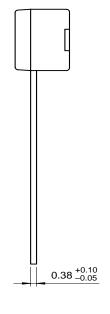


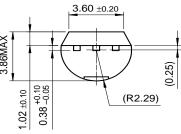
Figure 12. Power Dissipation vs Ambient Temperature

# **Package Dimensions**

TO-92

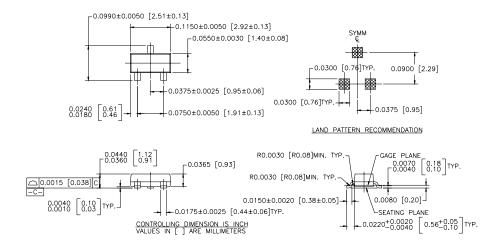






### Package Dimensions (Continued)

# SuperSOT-3



Dimensions in Millimeters

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